











SN74AUP1G00

SCES604I - SEPTEMBER 2004-REVISED JUNE 2014

# SN74AUP1G00 Low-Power Single 2-Input Positive-NAND Gate

#### **Features**

- Available in the Ultra Small 0.64 mm<sup>2</sup> Package (DPW) with 0.5-mm Pitch
- Low Static-Power Consumption  $(I_{CC} = 0.9 \mu A Max)$
- Low Dynamic-Power Consumption  $(C_{pd} = 4 pF Typ at 3.3 V)$
- Low Input Capacitance ( $C_i = 1.5 pF Typ$ )
- Low Noise Overshoot and Undershoot <10% of  $V_{CC}$
- I<sub>off</sub> Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input  $(V_{hys} = 250 \text{ mV Typ at } 3.3 \text{ V})$
- Wide Operating V<sub>CC</sub> Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal
- $t_{pd} = 4.8 \text{ ns Max at } 3.3 \text{ V}$
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)

## 2 Applications

- **ATCA Solutions**
- Active Noise Cancellation (ANC)
- Barcode Scanner
- **Blood Pressure Monitor**
- **CPAP Machine**
- Cable Solutions
- DLP 3D Machine Vision, Hyperspectral Imaging, Optical Networking, and Spectroscopy
- E-Book
- Embedded PC
- Field Transmitter: Temperature or Pressure Sensor
- Fingerprint Biometrics
- HVAC: Heating, Ventilating, and Air Conditioning
- Network-Attached Storage (NAS)
- Server Motherboard and PSU
- Software Defined Radio (SDR)
- TV: High-Definition (HDTV), LCD, and Digital
- Video Communications System
- Wireless Data Access Card, Headset, Keyboard, Mouse, and LAN Card
- X-ray: Baggage Scanner, Medical, and Dental

#### 3 Description

This single 2-input positive-NAND gate performs the Boolean function  $Y = \overline{A \times B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SOT-23 (5)	2.90 mm x 1.60 mm		
	SC70 (5)	2.00 mm × 1.25 mm		
SN74AUP1G00	SOT (5)	1.60 mm x 1.20 mm		
	USON (6)	1.45 mm × 1.00 mm		
	X2SON (4)	0.80 mm × 0.80 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## Simplified Schematic





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## **5 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

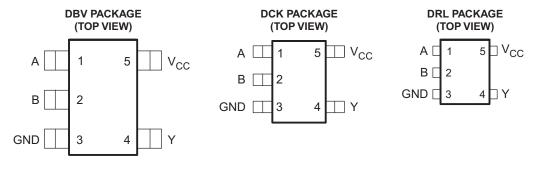
C	hanges from Revision H (April 2012) to Revision I	Page
•	Updated document to new TI data sheet format	1
•	Removed Ordering Information table.	1
•	Updated I <sub>off</sub> in Features.	1
•	Added Applications	1
•	Added Device Information table.	1
•	Added DPW Package.	3
•	Added Handling Ratings table	4
•	Added Thermal Information table.	5
•	Added Typical Characteristics	8
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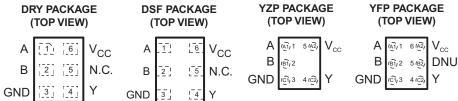
Changes from Revision G (March 2010) to Revision H

Product Folder Links: SN74AUP1G00



## 6 Pin Configuration and Functions





DNU – Do not use
N.C. – No internal connection
See mechanical drawings for dimensions.



#### **Pin Functions**

		P	IN				
NAME	DBV, DCK, DRL	DPW	DRY, DSF	YZP	YFP	I/O	DESCRIPTION
Α	1	2	1	A1	A1	1	Input A
В	2	1	2	B2	B2	I	Input B
GND	3	3	3	C3	В3	_	Ground
Υ	4	4	4	C4	C4	0	Output Y
VCC	5	5	6	A5	A6	_	Power Pin



## 7 Specifications

# 7.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
$V_{I}$	Input voltage range <sup>(2)</sup>		-0.5	4.6	٧
Vo	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>			4.6	V
Vo	Output voltage range in the high or low state <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		50	mA
Io	Continuous output current			20	mA
	Continuous current through V <sub>CC</sub> or GND	Continuous current through V <sub>CC</sub> or GND			mA

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 Handling Ratings

			MIN	MAX	UNIT	
T <sub>stg</sub>	Storage temperature rang	e	<del>-</del> 65	150	°C	
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	2000	\/	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V	

Product Folder Links: SN74AUP1G00

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.



## 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		0.8	3.6	V	
		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>			
.,	Litab laval innut valta sa	V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>		V	
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.6		V	
		V <sub>CC</sub> = 3 V to 3.6 V	2			
		V <sub>CC</sub> = 0.8 V		0		
,	Low lovel input veltage	V <sub>CC</sub> = 1.1 V to 1.95 V	0.:	35 × V <sub>CC</sub>	V	
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		V <sub>CC</sub> = 3 V to 3.6 V		0.9		
V <sub>I</sub>	Input voltage		0	3.6	V	
V <sub>O</sub>	Output voltage		0	$V_{CC}$	V	
		$V_{CC} = 0.8 \text{ V}$		-20	μΑ	
		V <sub>CC</sub> = 1.1 V		-1.1		
	High lovel output ourrent	V <sub>CC</sub> = 1.4 V		-1.7		
OH	nigir-level output current	$V_{CC} = 1.65$		-1.9	mA	
	oH High-level output current	$V_{CC} = 2.3 \text{ V}$		-3.1		
		$V_{CC} = 3 V$		-4		
		V <sub>CC</sub> = 0.8 V		20	Α	
		V <sub>CC</sub> = 1.1 V		1.1		
	Low-level output current	$V_{CC} = 1.4 \text{ V}$		1.7		
OL	Low-level output current	V <sub>CC</sub> = 1.65 V		1.9	mA	
		$V_{CC} = 2.3 \text{ V}$		3.1		
		V <sub>CC</sub> = 3 V		4		
∆t/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V		200	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## 7.4 Thermal Information

7.4	lermai imormation							
	THERMAL METRIC <sup>(1)</sup>	DBV	DCK	DPW	DRL	DRY	DSF	UNIT
	THERMAL METRIC	5 PINS	5 PINS	5 PINS	5 PINS	6 PINS	6 PINS	UNII
$R_{\theta JA}$	Junction-to-ambient thermal resistance	298.6	314.4	291.8	349.7	554.9	407.1	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	240.2	128.7	224.2	120.5	385.4	232.0	
$R_{\theta JB}$	Junction-to-board thermal resistance	134.6	100.6	245.8	171.4	388.2	306.9	°C/W
Ψлт	Junction-to-top characterization parameter	114.5	7.1	31.4	10.8	159.0	40.3	C/VV
ΨЈВ	Junction-to-board characterization parameter	133.9	99.8	245.6	169.4	384.1	306.0	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	195.4	n/a	n/a	n/a	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



#### 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T,	<sub>A</sub> = 25°C		T <sub>A</sub> = -40°C	to 85°C	UNIT	
PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	UNIT	
	I <sub>OH</sub> = -20 μA	0.8 V to 3.6 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> - 0.1			
	I <sub>OH</sub> = -1.1 mA	1.1 V	0.75 × V <sub>CC</sub>			0.7 × V <sub>CC</sub>			
	$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11			1.03			
\/	$I_{OH} = -1.9 \text{ mA}$	1.65 V	1.32			1.3		V	
$V_{OH}$	$I_{OH} = -2.3 \text{ mA}$	221/	2.05			1.97		V	
	$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9			1.85			
	I <sub>OH</sub> = -2.7 mA	2.1/	2.72			2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6			2.55			
	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V			0.1		0.1		
	I <sub>OL</sub> = 1.1 mA	1.1 V			0.3 × V <sub>CC</sub>		0.3 × V <sub>CC</sub>		
	I <sub>OL</sub> = 1.7 mA	1.4 V			0.31		0.37		
	I <sub>OL</sub> = 1.9 mA	1.65 V			0.31		0.35	V	
$V_{OL}$	I <sub>OL</sub> = 2.3 mA	227			0.31		0.33	V	
	I <sub>OL</sub> = 3.1 mA	2.3 V			0.44		0.45		
	I <sub>OL</sub> = 2.7 mA	3 V			0.31		0.33		
	$I_{OL} = 4 \text{ mA}$	3 V			0.44		0.45		
I <sub>I</sub> A or B input	$V_I = GND \text{ to } 3.6 \text{ V}$	0 V to 3.6 V			0.1		0.5	μΑ	
I <sub>off</sub>	$V_I$ or $V_O = 0$ V to 3.6 V	0 V			0.2		0.6	μΑ	
Δl <sub>off</sub>	$V_I$ or $V_O = 0$ V to 3.6 V	0 V to 0.2 V			0.2		0.6	μΑ	
I <sub>CC</sub>	$V_I = GND$ or $(V_{CC}$ to 3.6 V), $I_O = 0$	0.8 V to 3.6 V			0.5		0.9	μΑ	
ΔI <sub>CC</sub>	$V_I = V_{CC} - 0.6 V^{(1)}, I_O = 0$	3.3 V			40		50	μΑ	
^	V V an CND	0 V		1.5				pF	
C <sub>i</sub>	$V_I = V_{CC}$ or GND	3.6 V		1.5					
C <sub>o</sub>	V <sub>O</sub> = GND	0 V		3				pF	

<sup>(1)</sup> One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND.

# 7.6 Switching Characteristics, $C_L = 5 pF$

over recommended operating free-air temperature range, (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V <sub>cc</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		UNIT
	(INPUT)			MIN	TYP	MAX	MIN	MAX	
			0.8 V		16.6				
			1.2 V ± 0.1 V	2.6	7	13.8	2.1	17.1	
	A or D	V	1.5 V ± 0.1 V	2.9	5	9.2	2.9	11.1	20
t <sub>pd</sub>	A or B	Y	1.8 V ± 0.15 V	2	4	7.1	2	9	ns
			4.9	1.3	6.2				
			3.3 V ± 0.3 V	1	2.4	3.8	1	4.8	



## 7.7 Switching Characteristics, $C_L = 10 pF$

over recommended operating free-air temperature range, (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V		T,	= 25°C		T <sub>A</sub> = -	UNIT
	(INPUT)			MIN	TYP	MAX	MIN	MAX	
		0.8 V		18.9					
	A or B	Υ	1.2 V ± 0.1 V	3.2	8	15.7	3.1	18.8	ns
			1.5 V ± 0.1 V	2.9	5.8	10.5	2.9	12.1	
t <sub>pd</sub>			1.8 V ± 0.15 V	2	4.7	8.2	2	9.8	
			2.5 V ± 0.2 V	1.3	3.4	5.7	1.3	6.8	
			3.3 V ± 0.3 V	1	2.9	4.5	1	5.2	

## 7.8 Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range, (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V <sub>cc</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -	UNIT	
	(INPUT)	(001701)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		21.3				
	A or B	Y	1.2 V ± 0.1 V	3.6	9	17.3	3.1	21.5	ns
			1.5 V ± 0.1 V	2.9	6.5	11.6	2.9	14	
t <sub>pd</sub>			1.8 V ± 0.15 V	2	5.3	9.2	2	11.4	
			2.5 V ± 0.2 V	1.3	3.9	6.4	1.3	8	
			3.3 V ± 0.3 V	1	3.3	5.1	1	6.4	

## 7.9 Switching Characteristics, $C_L = 30 pF$

over recommended operating free-air temperature range, (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V <sub>cc</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> =		UNIT	
	(INPUT)	(001F01)		MIN	TYP	MAX	MIN	MAX		
	A or B	Υ	0.8 V		28.4					
					1.2 V ± 0.1 V	4.9	11.9	21.9	4.4	27.1
			1.5 V ± 0.1 V	2.9	8.6	14.7	2.9	17.7	ns	
t <sub>pd</sub>			1.8 V ± 0.15 V	2	7.1	11.5	2	14.2		
			2.5 V ± 0.2 V	1.3	5.3	8.1	1.3	10		
			3.3 V ± 0.3 V	1	4.5	6.5	1	8		

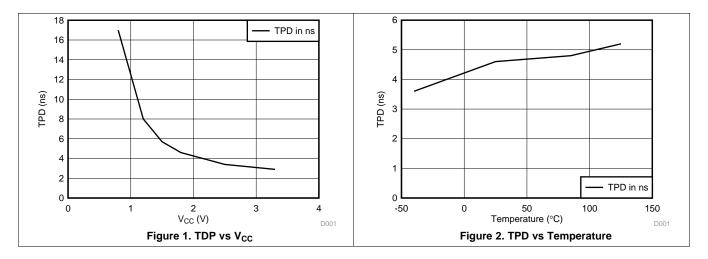
#### 7.10 Operating Characteristics

 $T_A = 25^{\circ}C$ 

<u> </u>				
PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	TYP	UNIT
		0.8 V	4	
		1.2 V ± 0.1 V	4	
Davis dissination associtance	f 40 MH-	1.5 V ± 0.1 V	4	F
Power dissipation capacitance	I = IU IVIMZ	1.8 V ± 0.15 V	4	pF
		2.5 V ± 0.2 V	4	
		3.3 V ± 0.3 V	4	
	PARAMETER  Power dissipation capacitance	PARAMETER TEST CONDITIONS		



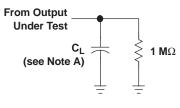
## 7.11 Typical Characteristics





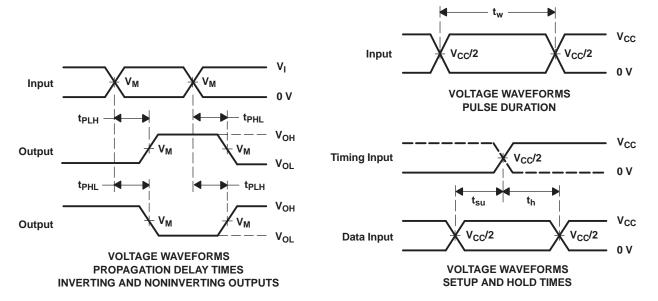
#### 8 Parameter Measurement Information

#### 8.1 Propagation Delays, Setup and Hold Times, and Pulse Width



**LOAD CIRCUIT** 

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	$V_{CC}$ = 1.8 V $\pm$ 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	$V_{CC}$ = 3.3 V $\pm$ 0.3 V
C <sub>L</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>



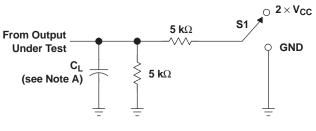
NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- $\begin{array}{ll} \text{D.} & t_{PLH} \text{ and } t_{PHL} \text{ are the same as } t_{pd}. \\ \text{E.} & \text{All parameters and waveforms are not applicable to all devices.} \end{array}$

Figure 3. Load Circuit and Voltage Waveforms



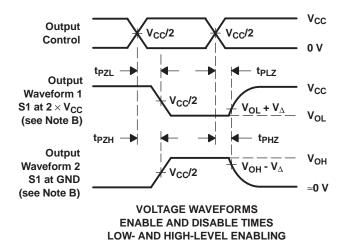
#### 8.2 Enable and Disable Times



TEST	S1
t <sub>PLZ</sub> /t <sub>PZL</sub>	2×V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

**LOAD CIRCUIT** 

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	V <sub>CC</sub> = 1.8 V ± 0.15 V	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
$\begin{array}{c} \textbf{C}_{\textbf{L}} \\ \textbf{V}_{\textbf{M}} \\ \textbf{V}_{\textbf{I}} \\ \textbf{V}_{\boldsymbol{\Delta}} \end{array}$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

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### 9 Detailed Description

#### 9.1 Overview

This is a single 2-input positive-NAND gate that is designed in Texas Instrument's ultra-low power technology. It performs the Boolean function  $Y = \overline{A} \times \overline{B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

The AUP family of devices has quiescent power consumption less than 1 µA and comes in the ultra small DPW package. The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered. The  $I_{off}$  feature also allows for live insertion.

#### 9.2 Functional Block Diagram



#### 9.3 Feature Description

- Wide operating V<sub>CC</sub> range of 0.8 V to 3.6 V
- 3.6-V I/O tolerant to support down translation
- · Input hysteresis allows slow input transition and better switching noise immunity at the input
- I<sub>off</sub> feature allows voltages on the inputs and outputs when V<sub>CC</sub> is 0 V
- · Low noise due to slower edge rates

#### 9.4 Device Functional Modes

**Table 1. Function Table** 

INF	PUTS	OUTPUT			
Α	В	Y			
L	L	Н			
L	Н	Н			
Н	L	Н			
Н	Н	L			

### 10 Application and Implementation

#### 10.1 Application Information

The AUP family is Tl's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity. It has a small amount of hysteresis built in allowing for slower or noisy input signals. The lowered drive produces slower edges and prevents overshoot and undershoot on the outputs.

#### 10.2 Typical Application

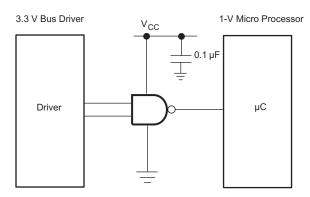


Figure 5. Typical Application Diagram

#### 10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits.

#### 10.2.2 Detailed Design Procedure

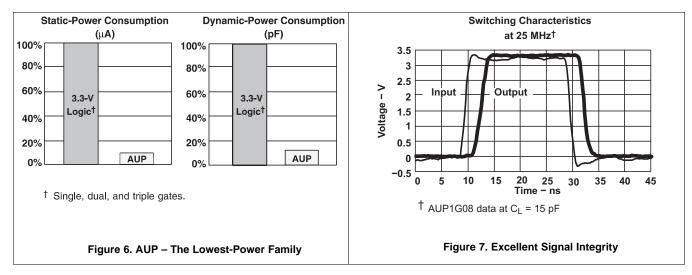
- 1. Recommended Input conditions
  - Rise time and fall time specs. See (Δt/ΔV) in Recommended Operating Conditions
  - Specified high and low levels. See (V<sub>IH</sub> and V<sub>IL</sub>) in Recommended Operating Conditions
  - Inputs are overvoltage tolerant allowing them to go as high as 3.6 V at any valid V<sub>CC</sub>
- 2. Recommend output conditions
  - Load currents should not exceed 20 mA on the output and 50 mA total for the part
  - Outputs should not be pulled above V<sub>CC</sub>

Submit Documentation Feedback



# Typical Application (continued)

#### 10.2.3 Application Curves



The AUP family of single gate logic makes excellent translators for the new lower voltage microprocessors that typically are powered from 0.8 V to 1.2 V. They can drop the voltage of peripheral drivers and accessories that are still powered by 3.3 V to the new uC power levels.



### 11 Power Supply Recommendations

The power supply can be any voltage between the Min and Max supply voltage rating located in the *Recommended Operating Conditions* table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$ F is recommended; if there are multiple  $V_{CC}$  pins, then 0.01  $\mu$ F or 0.022  $\mu$ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu$ F and a 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

## 12 Layout

#### 12.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 8 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

#### 12.2 Layout Example

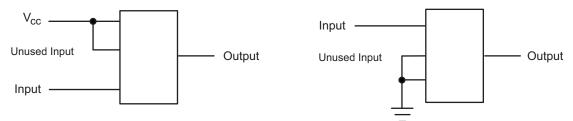


Figure 8. Layout Diagram

Submit Documentation Feedback



## 13 Device and Documentation Support

#### 13.1 Trademarks

All trademarks are the property of their respective owners.

#### 13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

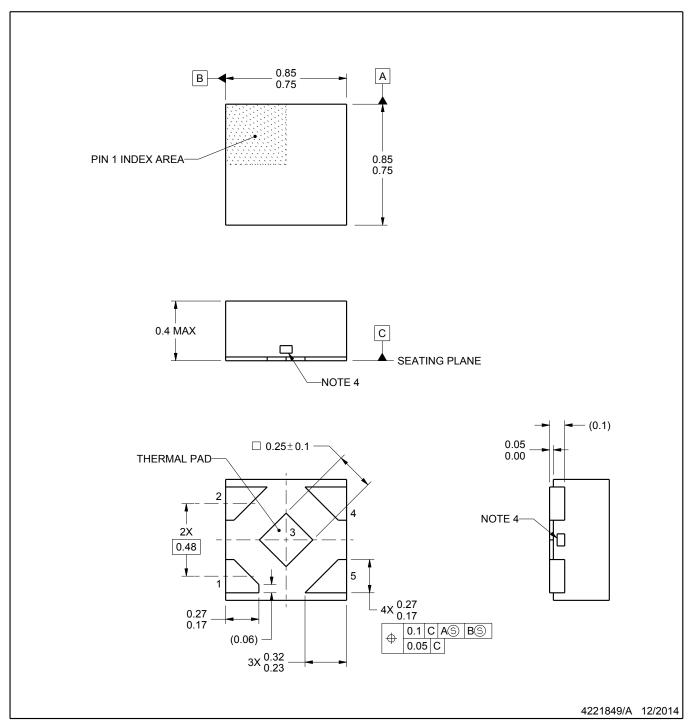
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## **PACKAGE OUTLINE**

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

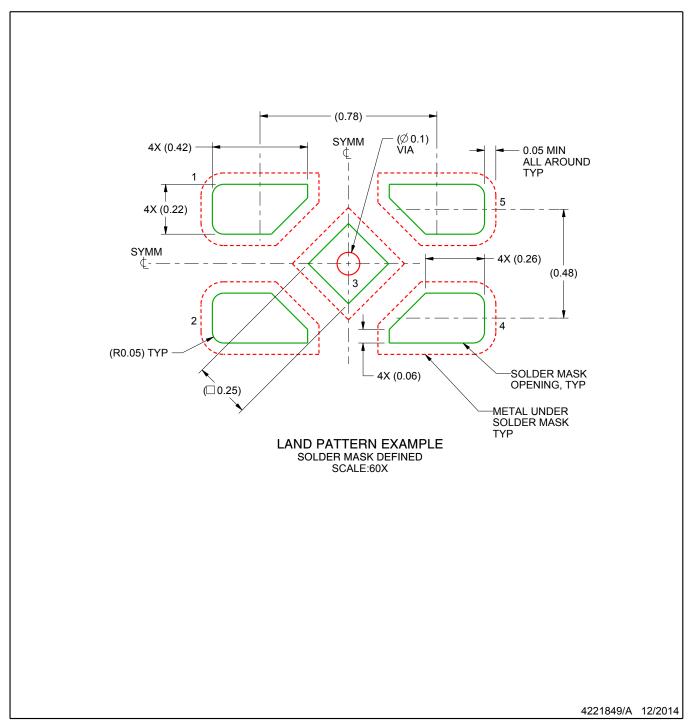


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

  4. The size and shape of this feature may vary.

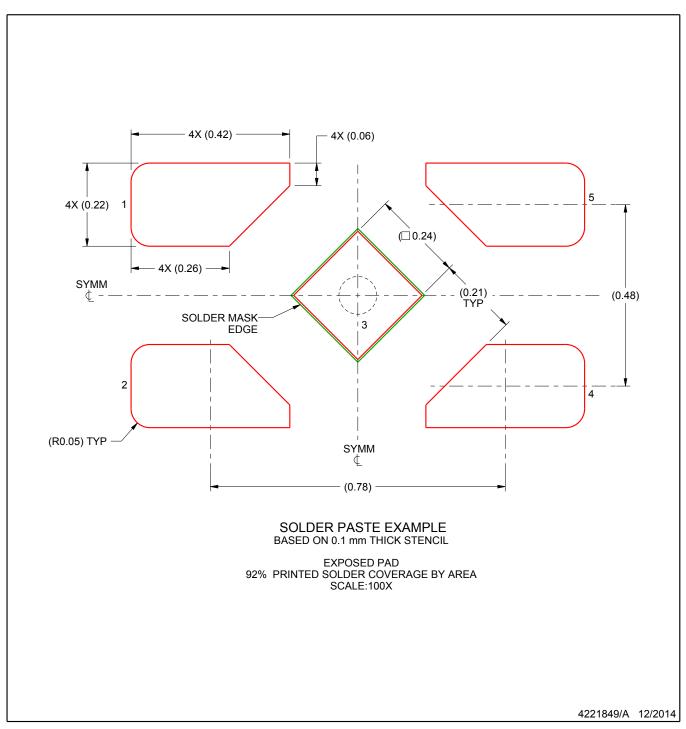




NOTES: (continued)

5. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







25-Oct-2016

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUP1G00DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H00R	Samples
SN74AUP1G00DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H00R	Samples
SN74AUP1G00DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H00R	Samples
SN74AUP1G00DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HAF ~ HAK ~ HAR)	Samples
SN74AUP1G00DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HAF ~ HAK ~ HAR)	Samples
SN74AUP1G00DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HAR	Samples
SN74AUP1G00DPWR	ACTIVE	X2SON	DPW	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	A4	Samples
SN74AUP1G00DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HA7 ~ HAR)	Samples
SN74AUP1G00DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HA7 ~ HAR)	Samples
SN74AUP1G00DRY2	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	НА	Samples
SN74AUP1G00DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	НА	Samples
SN74AUP1G00DSF2	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	НА	Samples
SN74AUP1G00DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	НА	Samples
SN74AUP1G00YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		(HA2 ~ HAN)	Samples
SN74AUP1G00YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	HAN	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



### PACKAGE OPTION ADDENDUM

25-Oct-2016

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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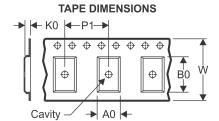
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 7-Sep-2016

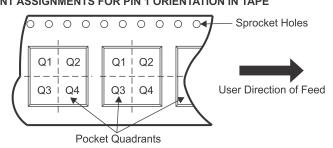
## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G00DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G00DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G00DCKR	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G00DCKR	SC70	DCK	5	3000	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AUP1G00DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G00DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74AUP1G00DRLR	SOT	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G00DRLR	SOT	DRL	5	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74AUP1G00DRY2	SON	DRY	6	5000	180.0	8.4	1.65	1.2	0.7	4.0	8.0	Q3
SN74AUP1G00DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74AUP1G00DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G00DSF2	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q3
SN74AUP1G00DSF2	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q3
SN74AUP1G00DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G00YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1
SN74AUP1G00YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

www.ti.com 7-Sep-2016



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G00DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G00DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G00DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G00DCKR	SC70	DCK	5	3000	205.0	200.0	33.0
SN74AUP1G00DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G00DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74AUP1G00DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G00DRLR	SOT	DRL	5	4000	184.0	184.0	19.0
SN74AUP1G00DRY2	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP1G00DRY2	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G00DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G00DSF2	SON	DSF	6	5000	184.0	184.0	19.0
SN74AUP1G00DSF2	SON	DSF	6	5000	202.0	201.0	28.0
SN74AUP1G00DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74AUP1G00YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0
SN74AUP1G00YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0

DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



# DBV (R-PDSO-G5)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC registration MO-287, variation X2AAF.







- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



# DCK (R-PDSO-G5)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



# DCK (R-PDSO-G5)

## PLASTIC SMALL OUTLINE

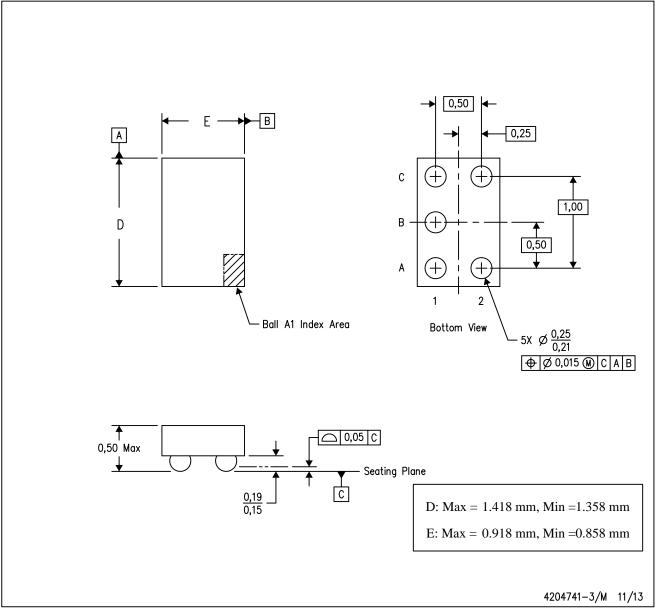


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree  $\mathbf{M}$  package configuration.

NanoFree is a trademark of Texas Instruments.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- The exposed lead frame feature on side of package may or may not be present due to alternative lead frame designs.
- E. This package complies to JEDEC MO-287 variation UFAD.
- $frac{f}{K}$  See the additional figure in the Product Data Sheet for details regarding the pin 1 identifier shape.



## DRY (R-PUSON-N6)

## PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

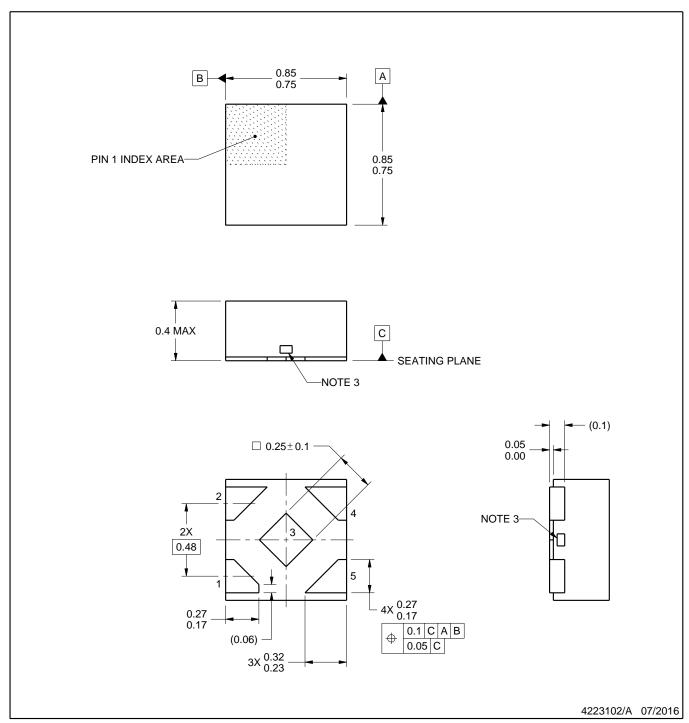




Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D

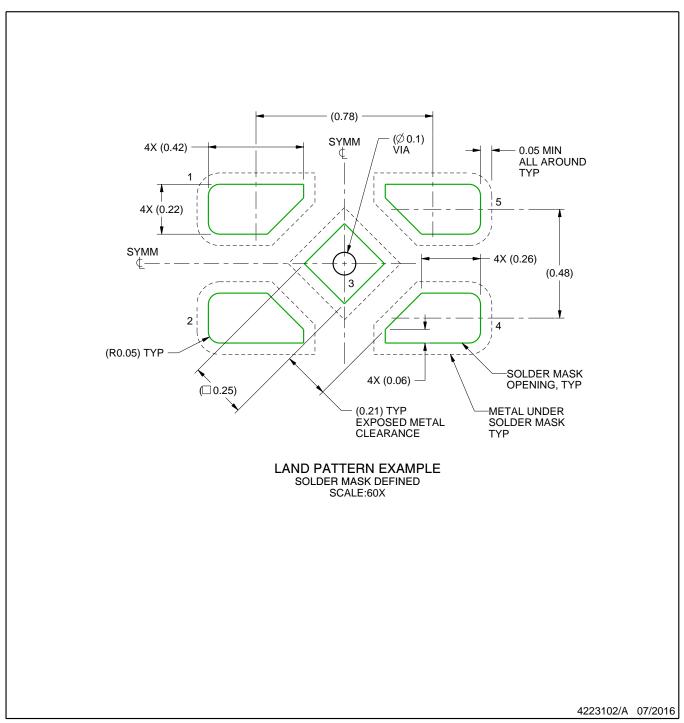




- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.

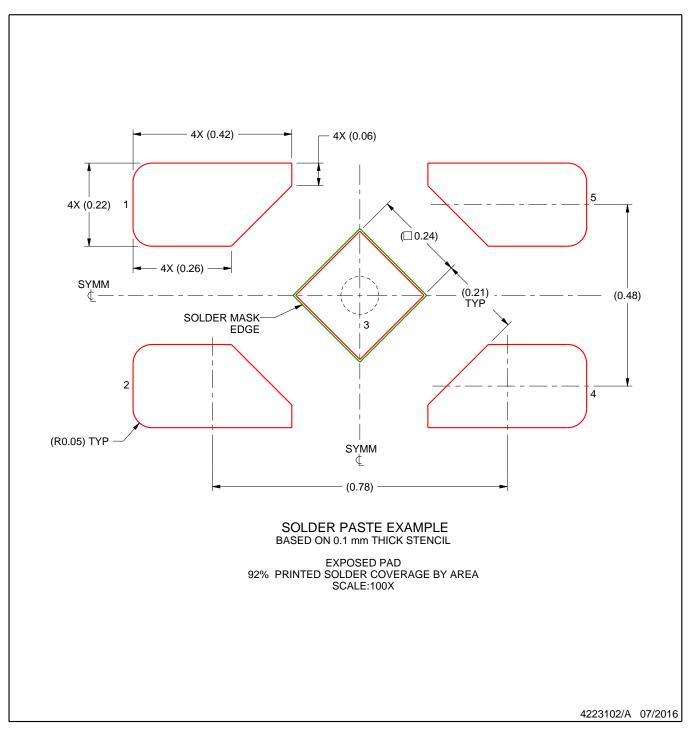




NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



# DRL (R-PDSO-N5)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

  Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



# DRL (R-PDSO-N5)

## PLASTIC SMALL OUTLINE



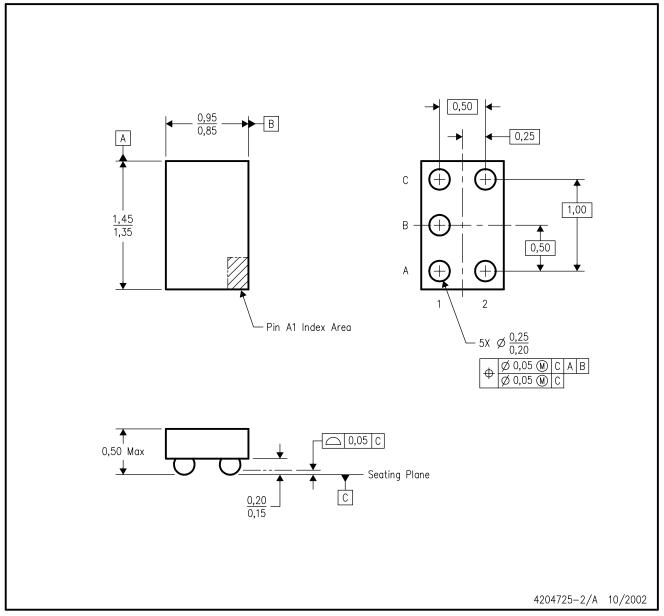
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



# YEP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

NanoStar is a trademark of Texas Instruments.



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